

30V Dual N-Channel MOSFET



Pin Definition: 1. Source 1 8. Drain 1

2. Gate 1	7. Drain 1
3. Source 2	6. Drain 2
4. Gate 2	5. Drain 2

PRODUCT SUMMARY

V _{DS} (V)	R _{DS(on)} (mΩ)	I _D (A)
20	19 @ V _{GS} = 10V	8.5
30	28 @ V _{GS} = 4.5V	6

Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

- Load Switch
- PWM Application

Ordering Information

Part No.	Package	Packing
TSM4416DCS RL	SOP-8	2.5Kpcs / 13" Reel

Block Diagram

Dual N-Channel MOSFET

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	30	V
Gate-Source Voltage		V _{GS}	20	V
Continuous Drain Current		I _D	8.5	А
Pulsed Drain Current		I _{DM}	40	А
Continuous Source Current (Diode Conduction) ^{a,b}		I _S	2.6	А
Maximum Power Dissipation	Ta = 25°C	- P _D	2.5	W
	Ta = 75°C		1.6	VV
Operating Junction Temperature		TJ	+150	°C
Operating Junction and Storage Temperature Range		T _J , T _{STG}	- 55 to +150	°C

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	RƏ _{JF}	25	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	Rθ _{JA}	50	°C/W

Notes:

a. Pulse width limited by the Maximum junction temperature

b. Surface Mounted on FR4 Board, t \leq 10 sec.



TSM4416D

30V Dual N-Channel MOSFET

Electrical Specifications (Ta = 25°C unless otherwise noted)

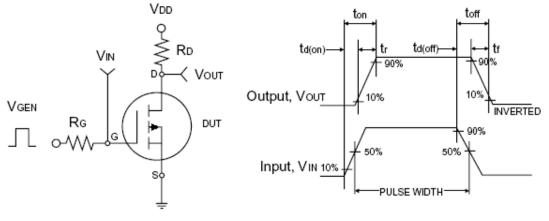
Parameter	Conditions	Symbol	Min	Тур	Мах	Unit
Static	1			1		
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_{D} = 250uA$	BV _{DSS}	30			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	V _{GS(TH)}	1	1.8	3	V
Gate Body Leakage	V_{GS} = ±20V, V_{DS} = 0V	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 24V, V_{GS} = 0V$	I _{DSS}			-1.0	μA
On-State Drain Current ^a	V _{DS} ≥ 5V, V _{GS} = 10V	I _{D(ON)}	40			Α
Drain-Source On-State Resistance ^a $V_{GS} = 10V, I_D = 8.5A$ $V_{GS} = 4.5V, I_D = 6A$ $R_{DS(ON)}$	V _{GS} = 10V, I _D = 8.5A			15.5	19	
		23	28	mΩ		
Forward Transconductance ^a	$V_{DS} = 5V, I_{D} = 8.5A$	g _{fs}		23		S
Diode Forward Voltage	I _S = 1A, V _{GS} = 0V	V _{SD}		0.71	1.0	V
Dynamic ^b						
Total Gate Charge		Qg		19	24	
Gate-Source Charge	$V_{DS} = 15V, I_D = 8.5A,$	Q _{gs}		9.36	12	nC
Gate-Drain Charge	$V_{GS} = 5V$	Q _{gd}		4.2		
Input Capacitance		C _{iss}		1040		
Output Capacitance	$V_{DS} = 15V, V_{GS} = 0V,$	C _{oss}		180		pF
Reverse Transfer Capacitance	f = 1.0MHz	C _{rss}		110		
Switching ^c						
Turn-On Delay Time		t _{d(on)}		5.2		
Turn-On Rise Time	$V_{DD} = 15V, R_{L} = 1.8\Omega,$	tr		4.4		
Turn-Off Delay Time	$I_D = 1A, V_{GEN} = 10V,$	t _{d(off)}		17.3		nS
Turn-Off Fall Time	$R_{G} = 3\Omega$	t _f		3.3		

Notes:

a. pulse test: PW ≤300µS, duty cycle ≤2%

b. For DESIGN AID ONLY, not subject to production testing.

b. Switching time is essentially independent of operating temperature.



Switching Test Circuit

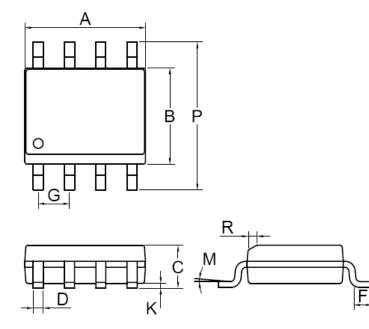
Switchin Waveforms



30V Dual N-Channel MOSFET

TSM4416D

SOP-8 Mechanical Drawing



SOP-8 DIMENSION					
DIM	MILLIMETERS		INCHES		
DIVI	MIN	MAX	MIN	MAX.	
Α	4.80	5.00	0.189	0.196	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.05	BSC	
K	0.10	0.25	0.004	0.009	
М	0°	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

Marking Diagram



Y = Year Code

M = Month Code (A=Jan, B=Feb, C=Mar, D=Apl, E=May, F=Jun, G=Jul, H=Aug, I=Sep, J=Oct, K=Nov, L=Dec)

L = Lot Code





Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.